

Characterisation of a 3D-stc p-type prototype module read out with ATLAS SCT electronics

9th RD 50 Workshop

17.Oct.2006

Physical Institute – University of Freiburg

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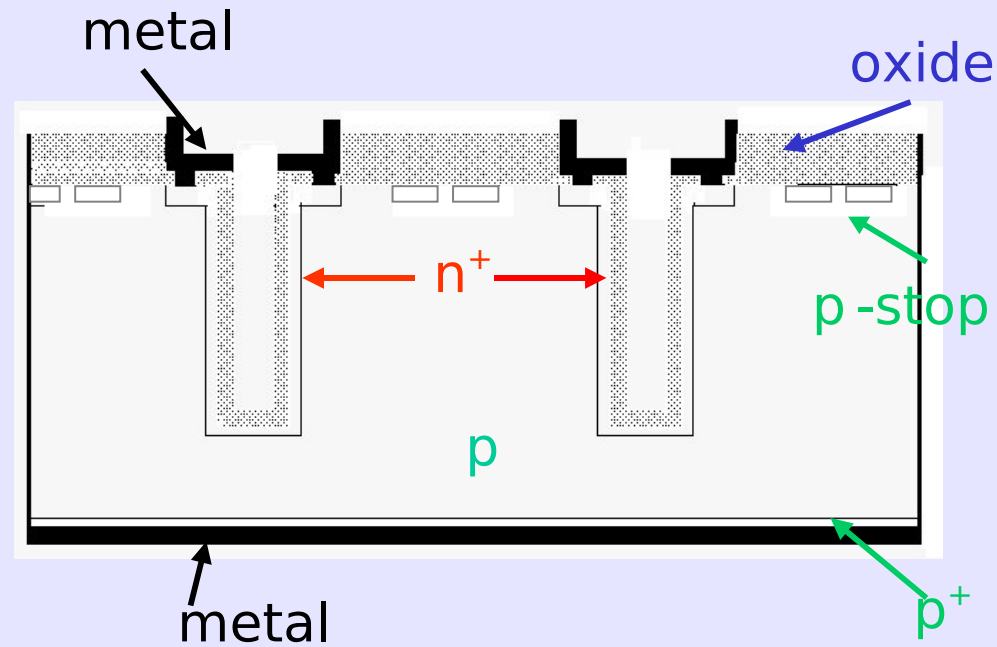
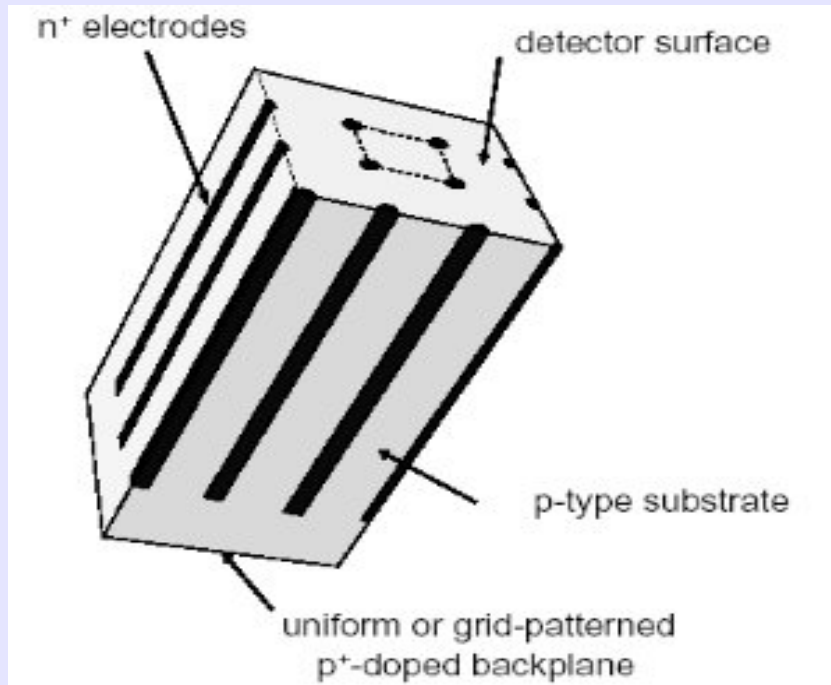
Outline

- Assembly of 3D prototype module
- Description of the laser test set-up
- Spatial measurements with laser test set-up
- Beta CCE measurements of irradiated stFZ module
- Summary and Outlook



3d-stc sensor

- 3D-stc FZ n^+ -in-p micro strip device from ITC-irst, Trento



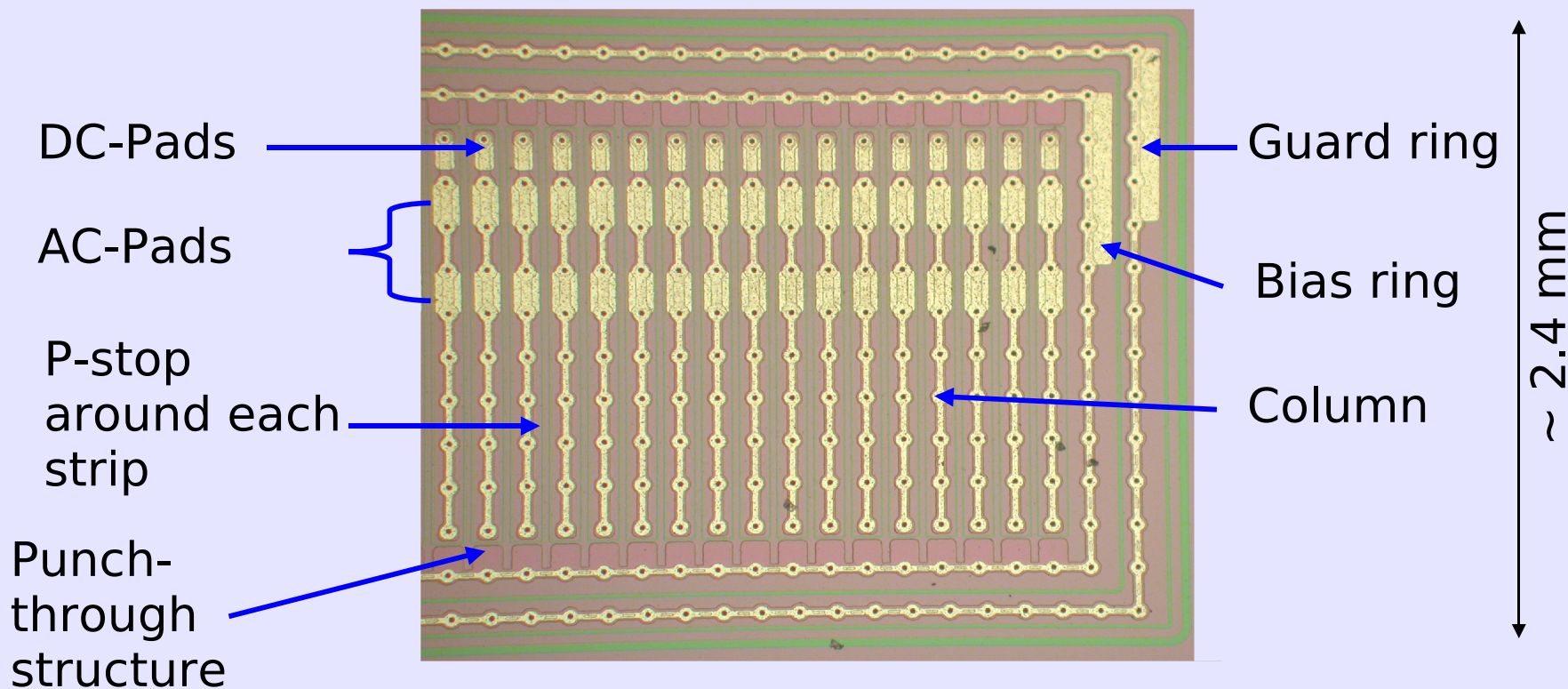
[C. Piemonte et al., NIM A 541 (2005) 441-448]

- sensor size: 2.4 mm x 7 mm , thickness: 500 μm , strip pitch: 80/100 μm
- 64 strips with each 10 columns, columns connected by n-doped layer
- resistivity 5 kOhm



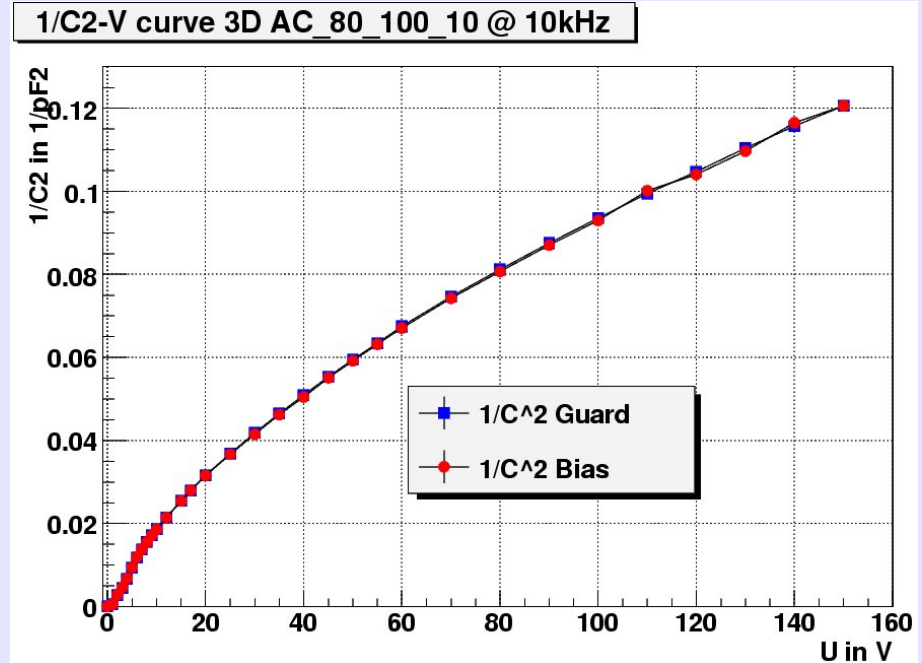
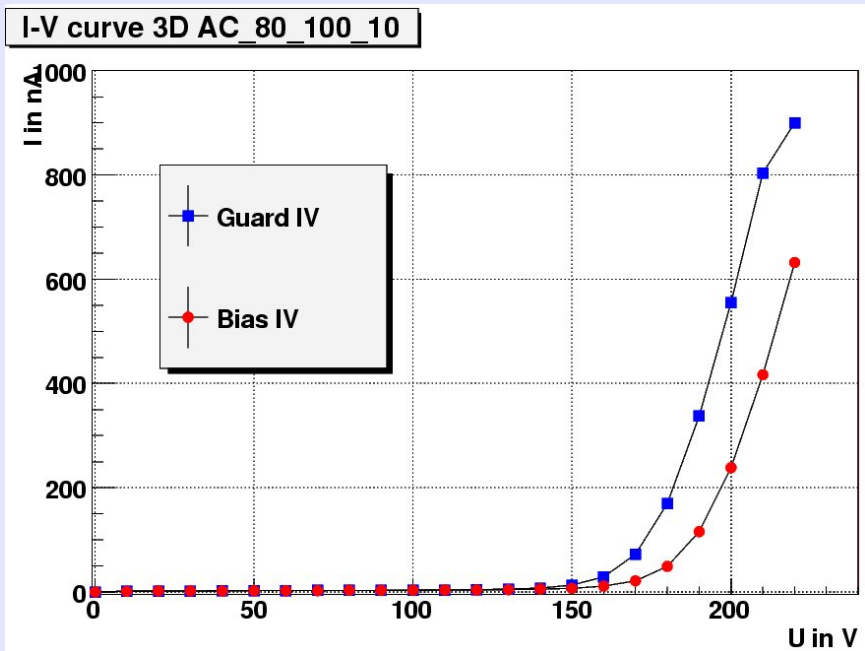
3d-stc sensor: AC_80_100_10

- AC coupling, punch-through structure
- strip pitch: 80 μm , interstrip pitch: 100 μm , hole diameter 10 μm
- common p-stop for each strip





IV and CV measurements



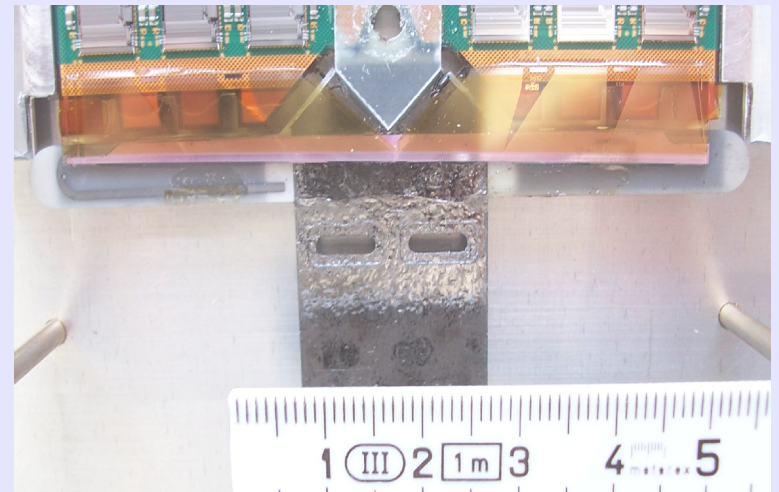
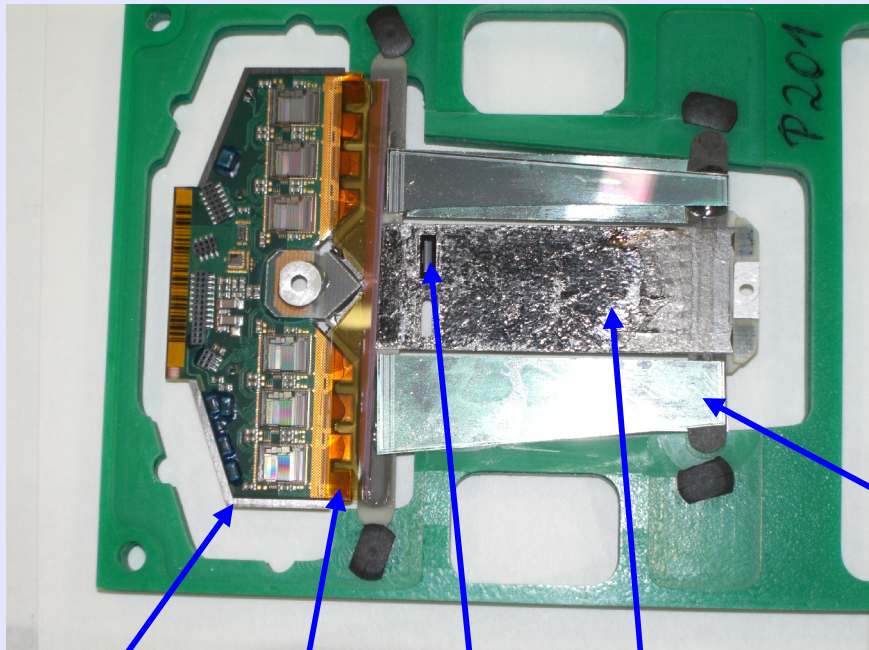
- IV-curves show breakthrough at $V_{\text{bias}} \approx 150 \text{ V}$
→ functional sensor

- lateral depletion around 7 V expected



Assembly of 3D module

- 3D-stc sensor AC_80_100_10
- Fan-ins from middle SCT modules (pitch = 92 μm) and SCT hybrid
- re-use of old spine: TPG material with slots for 3D-sensor



SCT hybrid

Fan-in

3D-sensor

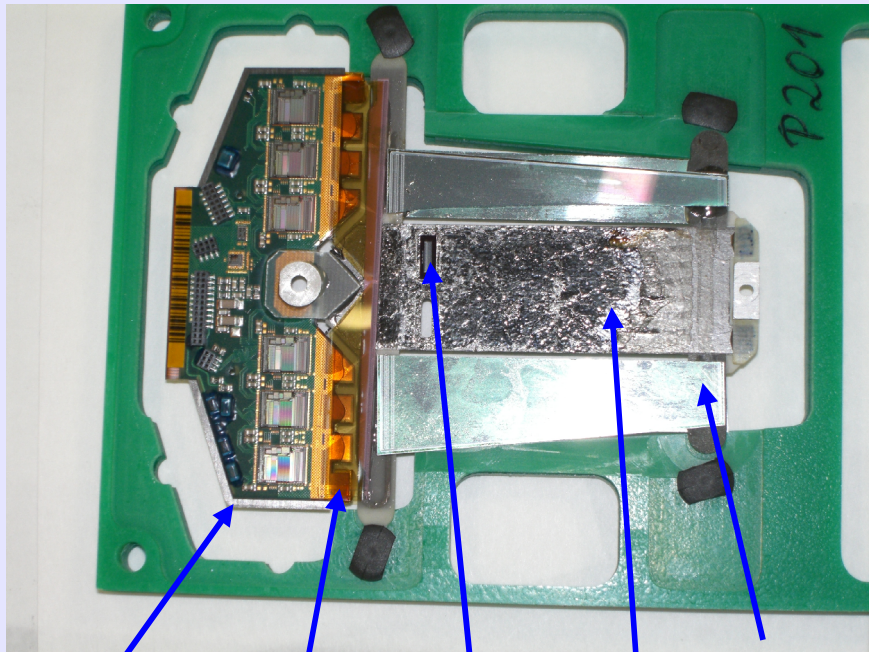
TPG for cooling

Old Si for stabilization



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SCT hybrid

Fan-in

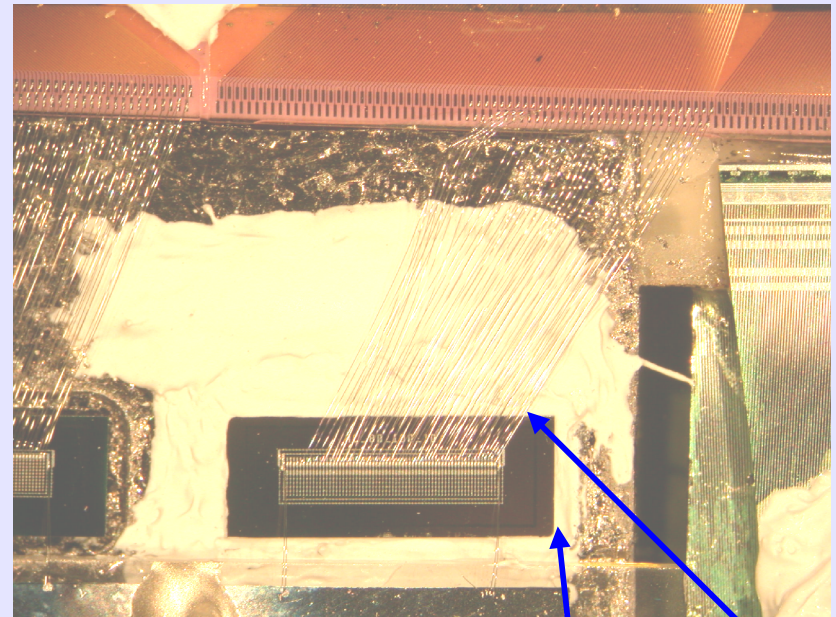
3D-sensor

TPG for cooling

Old Si for stabilisation

Oct. 17th 2006

9th RD50 workshop CERN



~ 7 mm

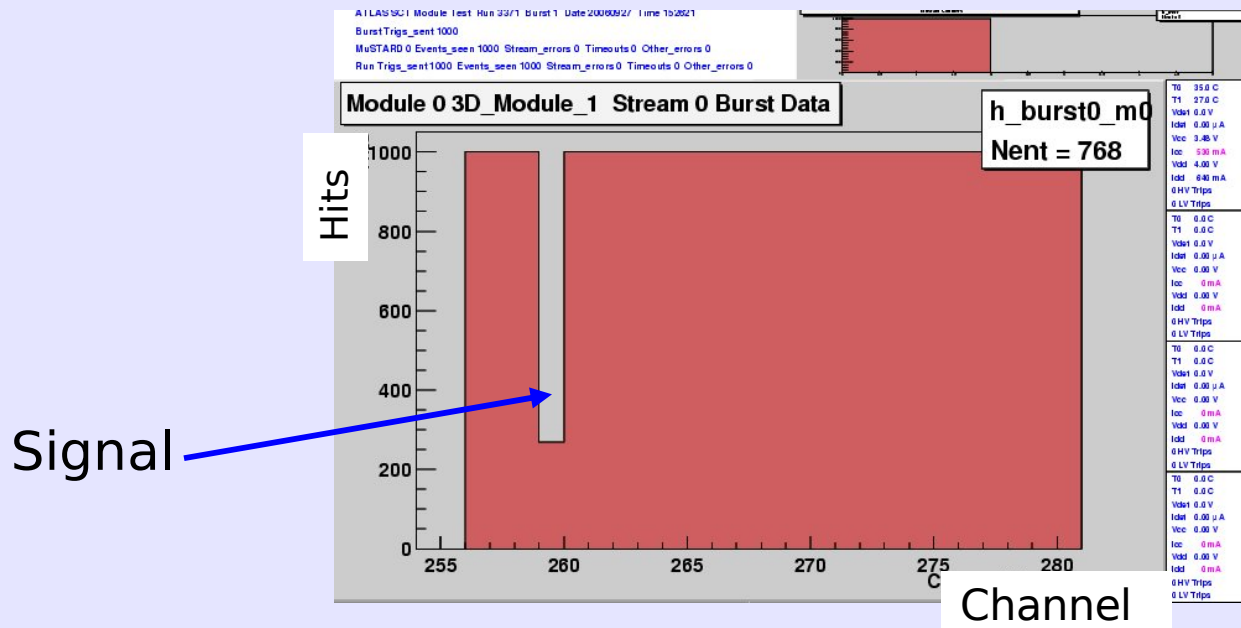
Thermal glue

Bond wires



ATLAS SCT Readout

- We use SCTDAQ and standard SCT hardware (VME, NIM)
- 40 MHz binary readout
- Peaking time of shaper 20 ns
- SCT ABCD3T chip is mostly bipolar, but discriminator is not
 - signals from p-type sensors are negative → TrimDAC
 - “maximal” signal @ 0 fC threshold, corresponds to ≈ -4 fC charge





The Laser set-up

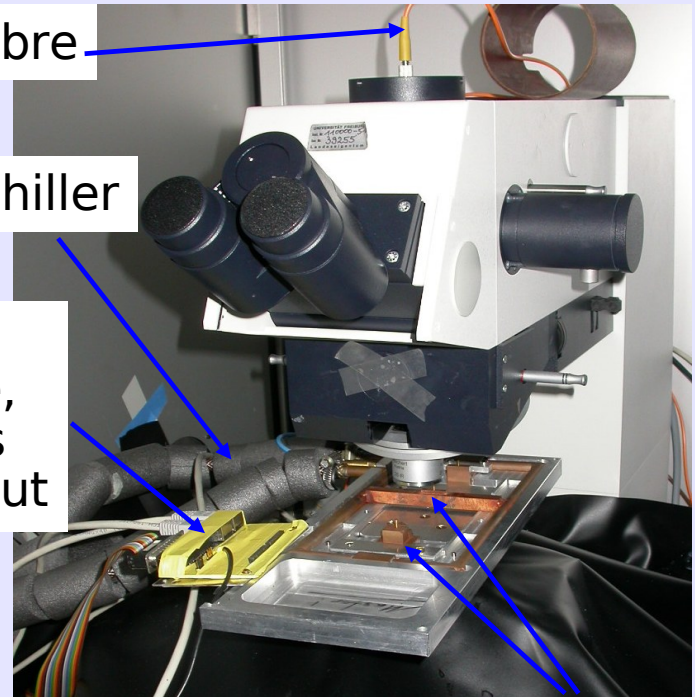
- Penetration depth of photons $\sim 100 \mu\text{m}$ @ 982 nm wavelength
- Length of one pulse $\sim 1\text{-}2 \text{ ns}$
- Focussing with the help of Leica-polyvar microscope, laserspot $\sim 2\text{-}3 \mu\text{m}$
- Moving of the sensors in x-y plane via motor-driven stages.
- Sensor is cooled to $-5 \text{ }^\circ\text{C}$
- built by Thies Ehrich

→ Testing of individual strips and interstrip area possible with automated x-y-stages, easy triggering, good time resolution (pulse $< 2 \text{ ns}$)

optical fibre

tubes from chiller

patch card for voltage, commands and read out

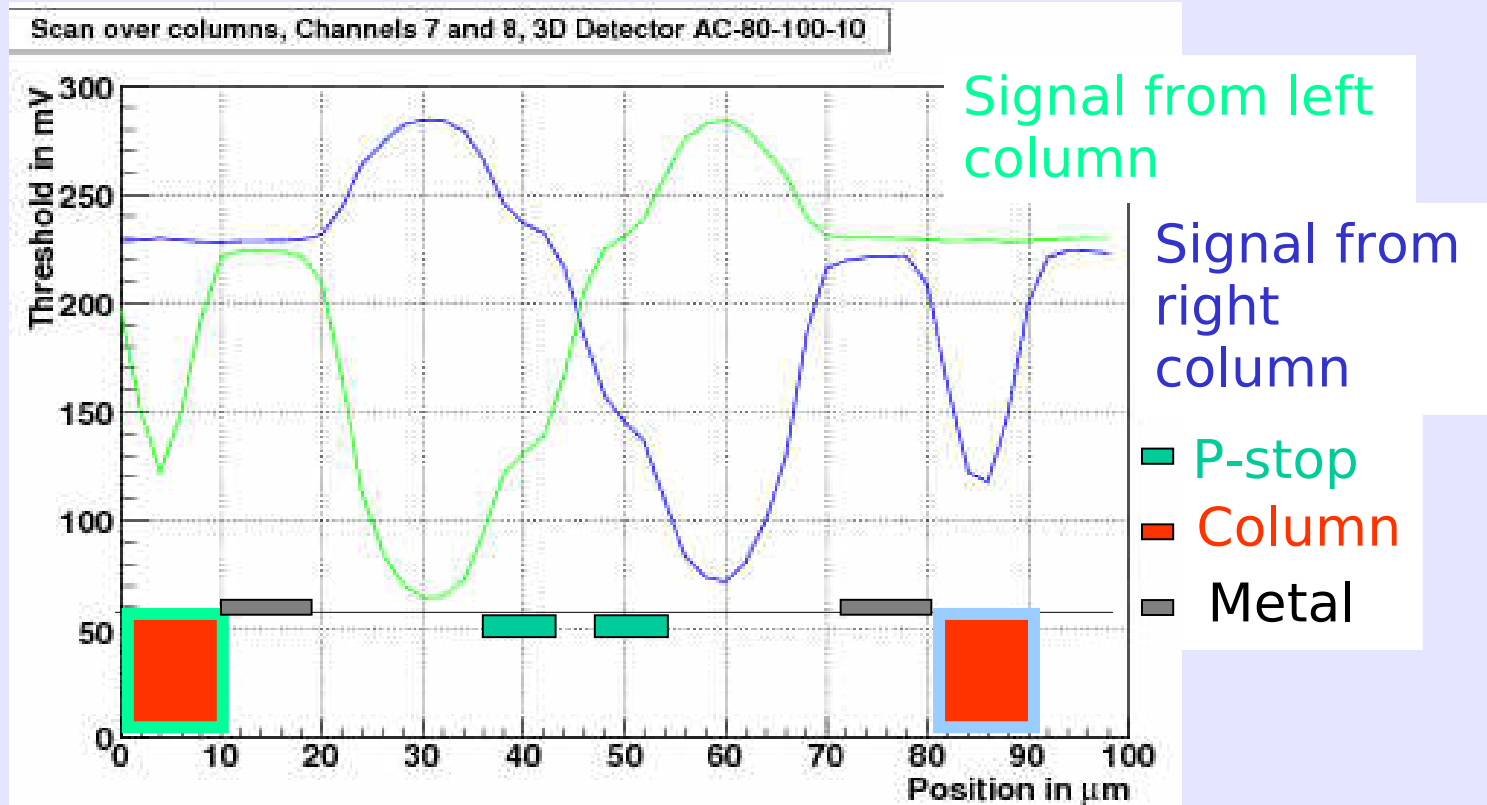


cooling is provided close to the front end and the far end of the sensor



Laser measurements

- Scan over two columns at $V_{\text{bias}} = 12 \text{ V}$:

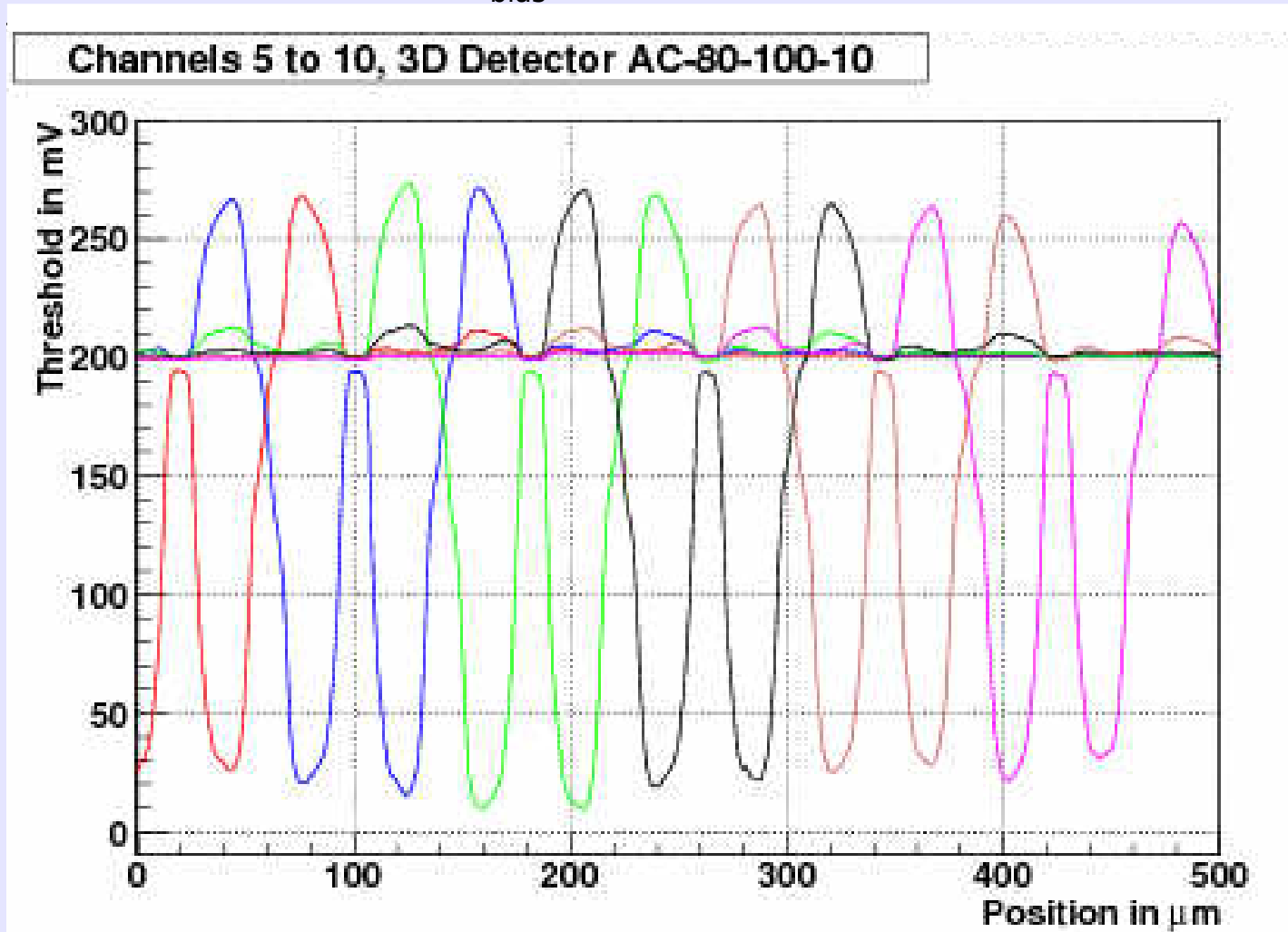


- positive signal on neighbouring strips
- p-stop structure can be seen



Laser measurements

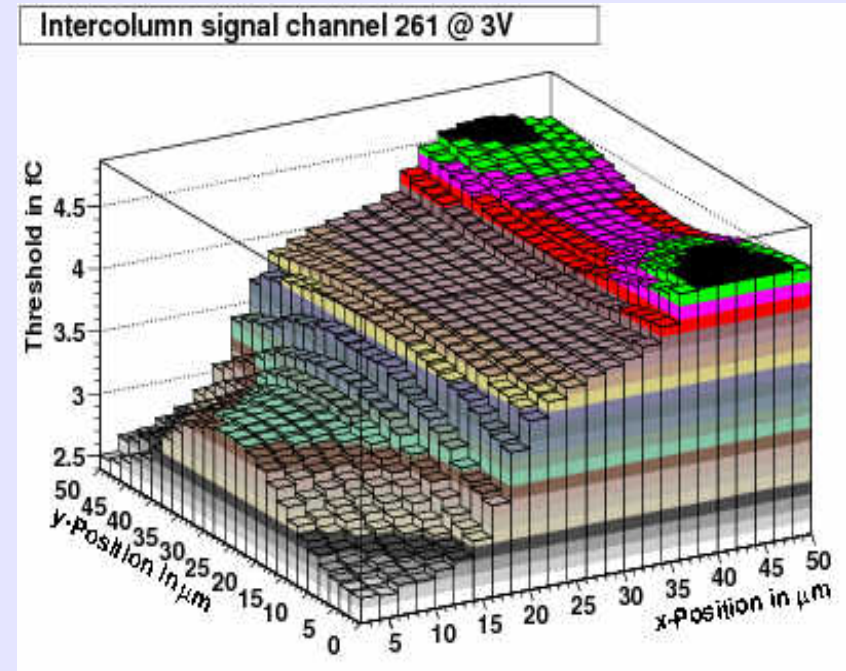
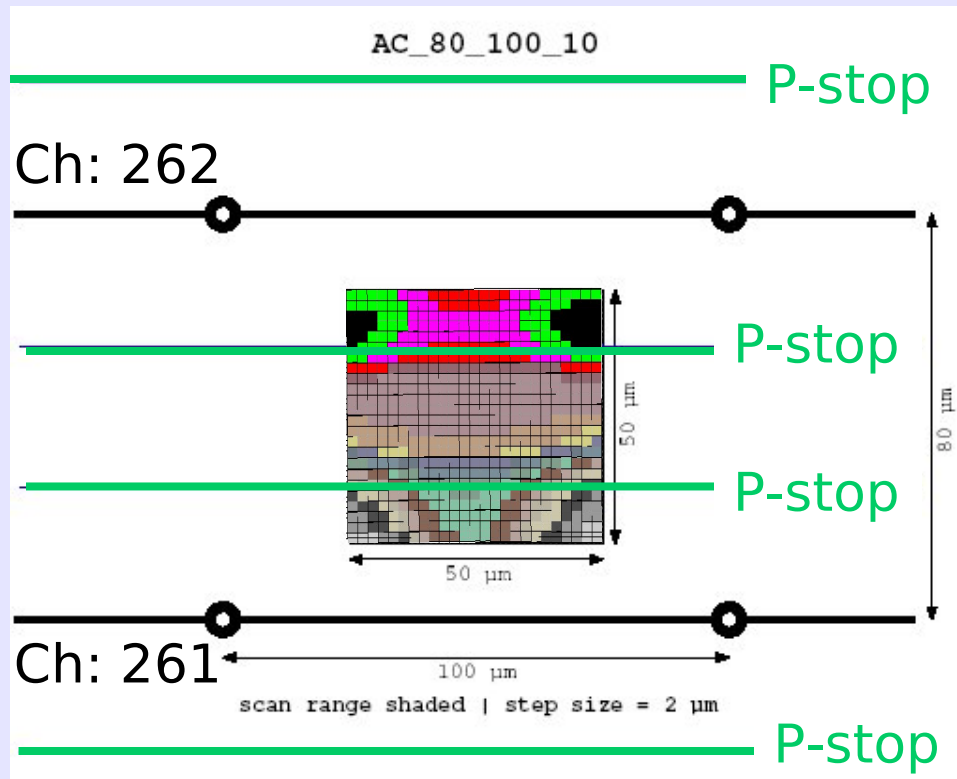
- Scan over 6 columns at $V_{\text{bias}} = 12 \text{ V}$:





Spatial measurements

- Scan over 50 μm x 50 μm region between two strips for several bias voltages:

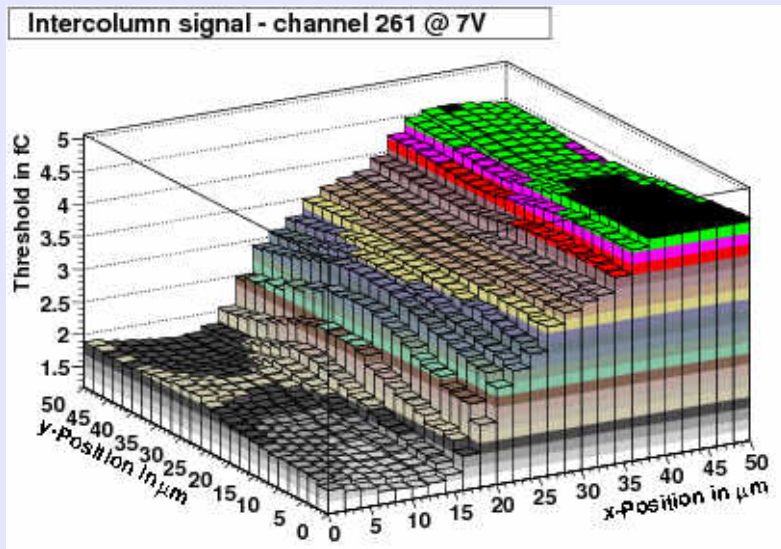


$$V_{\text{bias}} = 3 \text{ V}$$

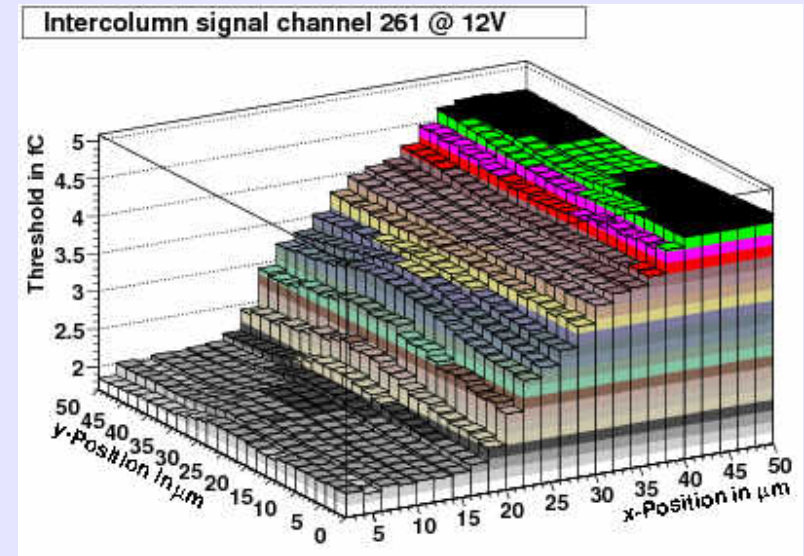


Spatial measurements

$V_{\text{bias}} = 7 \text{ V}$:



$V_{\text{bias}} = 12 \text{ V}$:

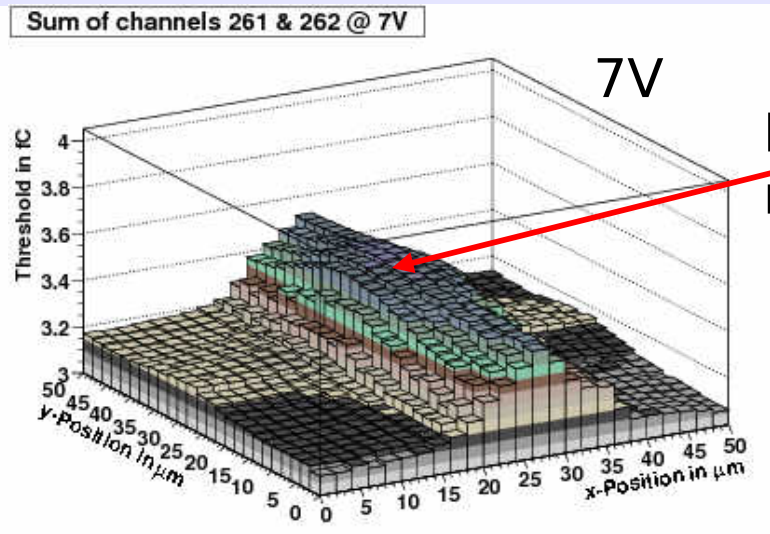
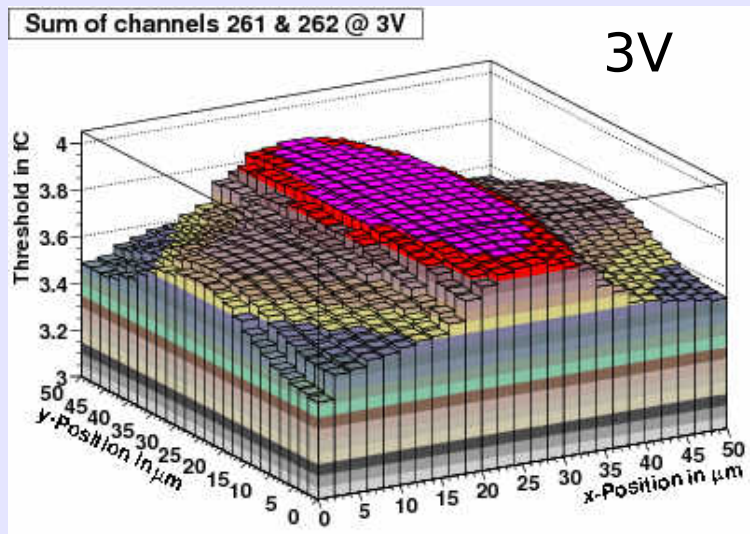


- Noise: Nearly same amplitude as unbonded channels, can not be measured → low interstrip capacitance because of short strips

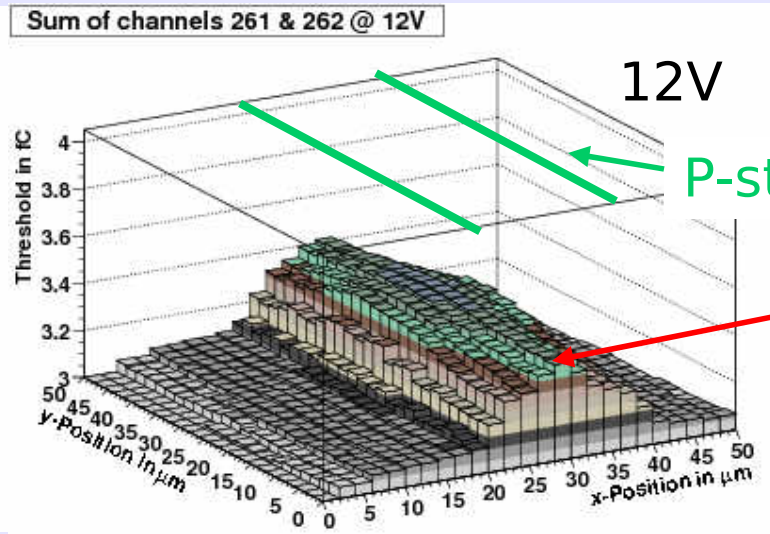
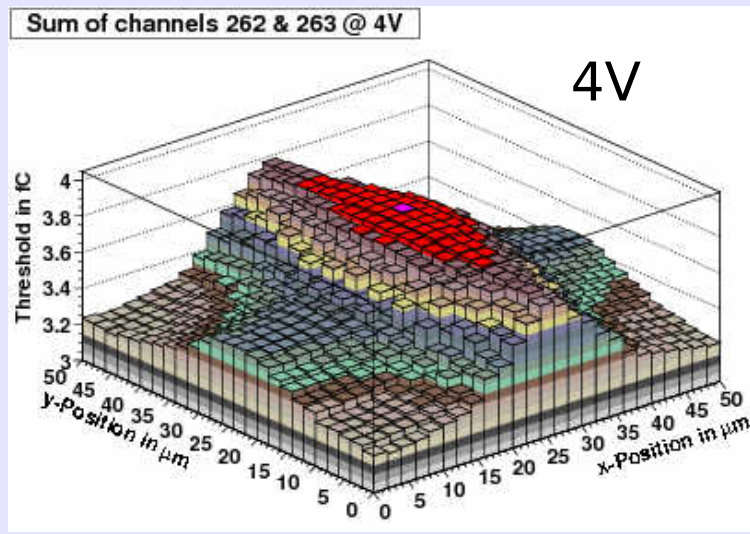


Spatial measurements

- Scans from 2 channels added



Low signal region



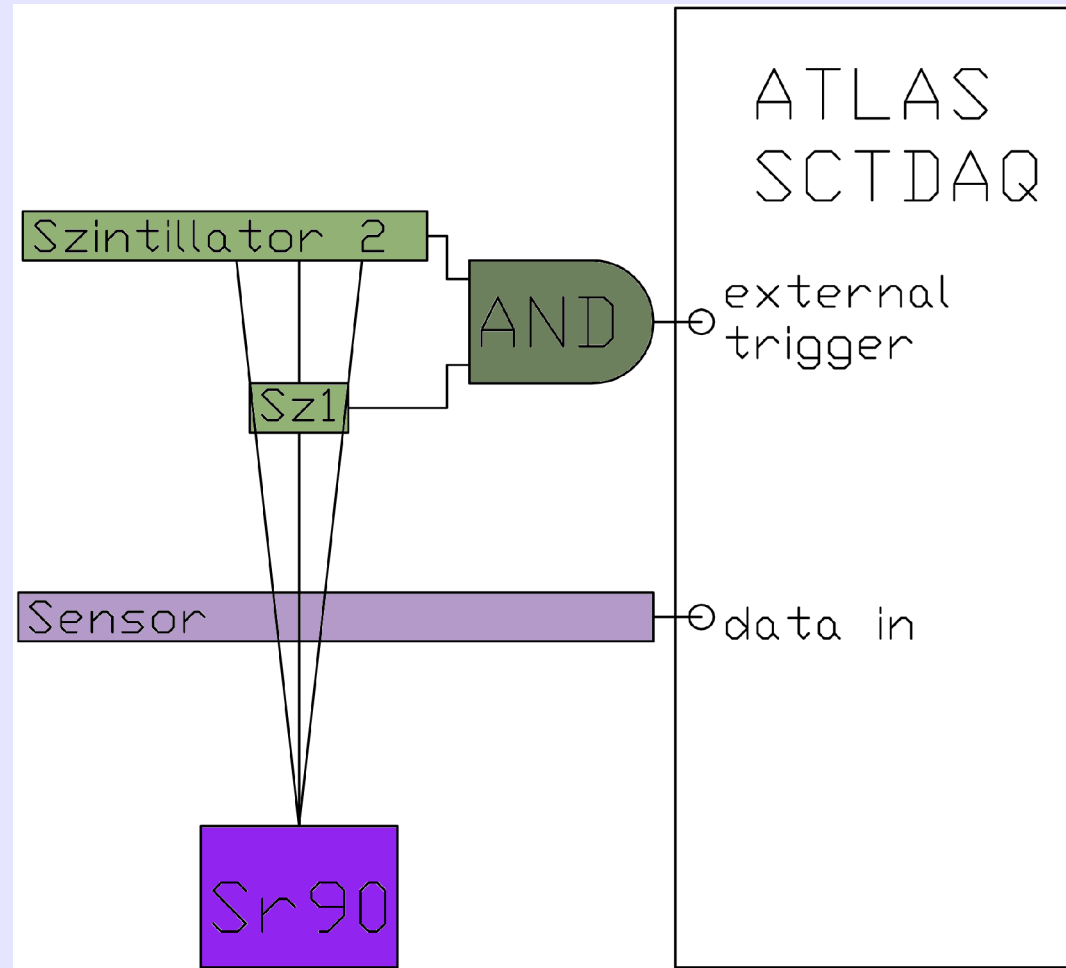
P-stop

P-Stop reduces signal



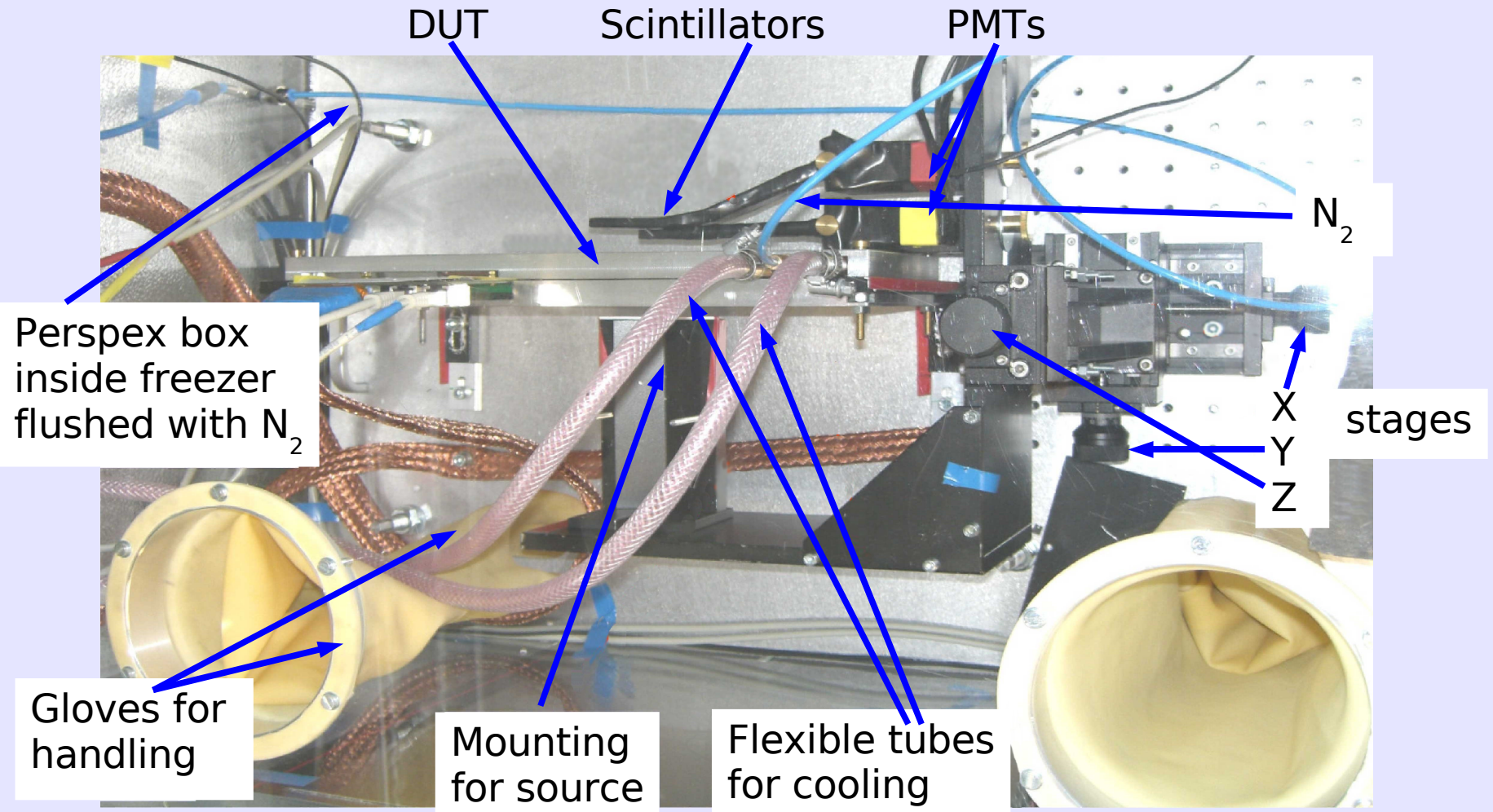
Beta source set-up

- 2.4 MBq ^{90}Sr source
- Sufficiently high energy electrons simulate MIPs
- Binary readout
- 40 MHz clock
- 20 ns peaking time of shaper
- Temperature $< -11^\circ\text{C}$ (hybrid thermistor)



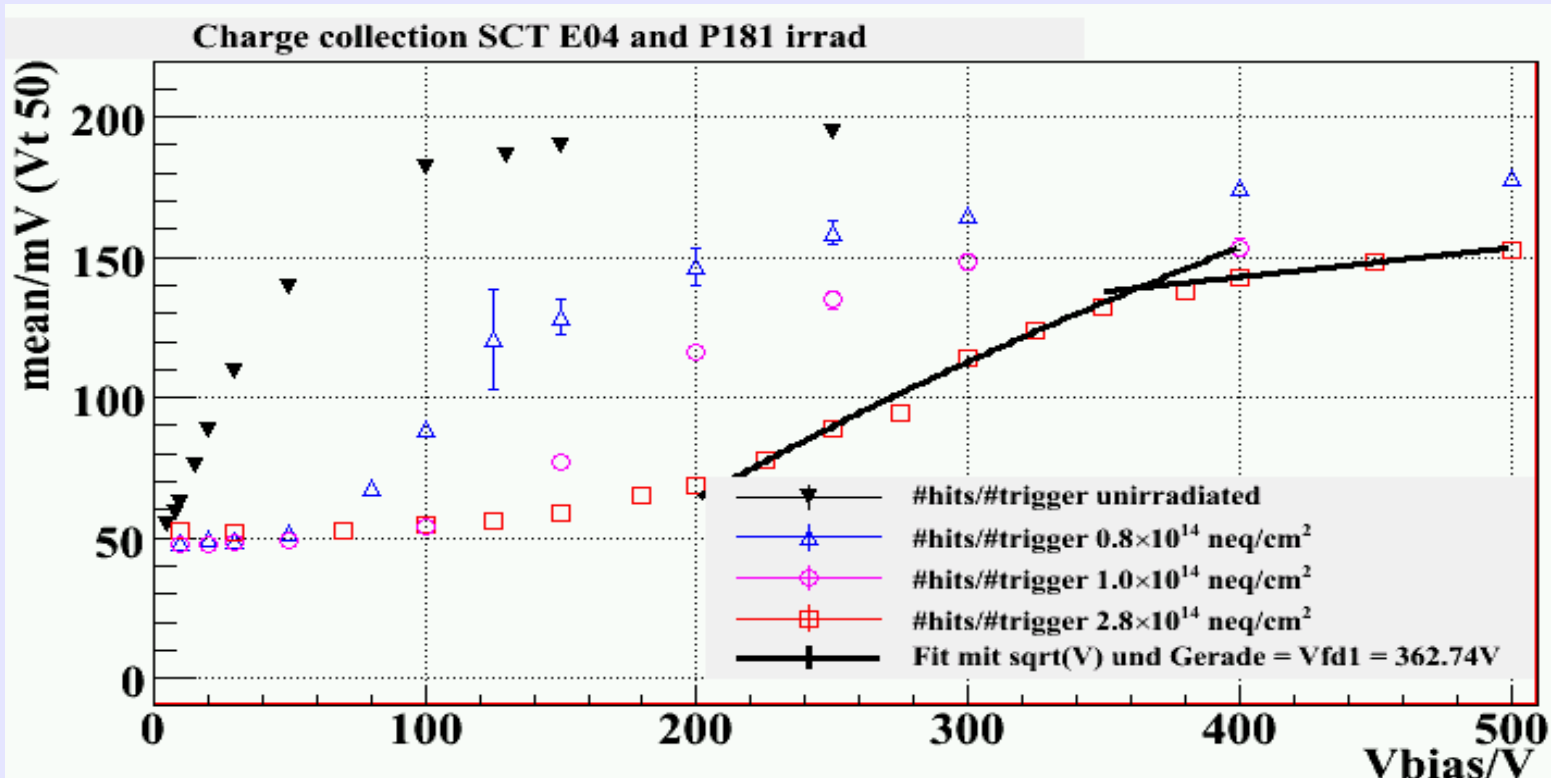


Beta source set-up





Beta measurements with stFZ p-in-n sensors



Irradiation done with
26 MeV protons
in Karlsruhe
Thanks to A.Furgeri

Unirradiated

$$\phi_1 = 0.8 \cdot 10^{14} \text{ neq/cm}^2 (\pm 10\%)$$

$$\phi_2 = 1.0 \cdot 10^{14} \text{ neq/cm}^2 (\pm 10\%)$$

$$\phi_3 = 2.8 \cdot 10^{14} \text{ neq/cm}^2 (\pm 10\%)$$

$$\rightarrow V_{fd} = 89 \text{ V}$$

$$\rightarrow V_{fd} = 180 \text{ V}$$

$$\rightarrow V_{fd} = 257 \text{ V}^*$$

$$\rightarrow V_{fd} = 363 \text{ V}$$



Summary and Outlook

- Absolute and relative CCE measurements possible
- For stFZ S/N decreases from 25 to 16 (un-irradiated hybrid)
- 3D module:
- first measurements with LHC-speed electronics of 3D-stc sensor
- large (15 μm) low-field region between columns
- P-stops may have impact on electric field \rightarrow signal reduced

To do for 3D module:

- measure charge collection efficiency with beta source set-up
- measure sensors with different p-stops
- irradiate sensors, then re-characterise

Thanks to colleagues from IRST, Trento, MPI Munich and Prague